

HITANO

ENTERPRISE CORP. ®

HITANO ENTERPRISE CORP.**DLQ4148 AND DLQ4448****TECHNICAL SPECIFICATIONS OF SURFACE MOUNT SWITCHING DIODES****VOLTAGE RANGE - 100 Volts****CURRENT - 0.15 Ampere****FEATURES**

- * Low power loss, high efficiency
- * Low leakage
- * Low forward voltage drop
- * High speed switching
- * High current capability
- * High reliability

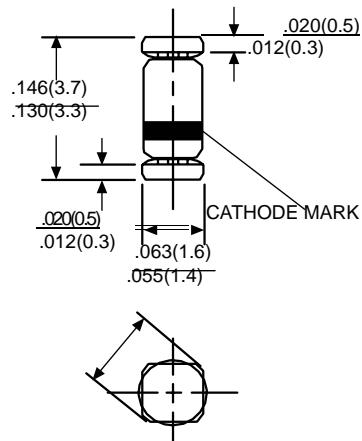
MECHANICAL DATA

- * Case: Glass sealed case Quadro Melf
- * Terminals: Solder plated, solderable per MIL-STD-750, Method 2026 guaranteed
- * Polarity: Color band denotes cathode end
- * Mounting position: Any
- * Weight: 0.05 grams Approx.

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25 °C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate current by 20%.

**Quadro Melf**

Dimensions in inches and (millimeters)

	SYMBOL	DLQ4148	DLQ4448	UNITS
Maximum Reverse Voltage	VR	75		V
Maximum Recurrent Peak Reverse Voltage	V _{RRM}	100		V
Maximum Average Rectified Current	I _o	150		mA
Peak Forward Surge Current 8.3 ms single half sine-wave superimposed on rated load (JEDEC Method)	I _{FSM}	0.5		A
Maximum Power Dissipation Tamb=25°C	P _{tot}	500		mW
Maximum Forward Voltage	V _F	1.0 / 10mA	0.72 / 5mA 1.0 / 10mA	V
Maximum Reverse Current at Rated DC Blocking Voltage @ TA=25°C	I _R	5.0		µA
Maximum Reverse Recovery Time(Note 1)	t _{rr}	4.0		ns
Typical Junction Capacitance(Note 2)	C _J	4.0		pF
Operating and Storage Temperature Range	T _{J,TSTG}	-55 to + 125		°C

Note: 1. Test conditions: I_F=I_R=10mA, R_L=100Ω, measured at I_R=1mA2. Measured at 1MHz and V_R=0

RATING AND CHARACTERISTIC CURVES (DLQ4148 AND DLQ4448)

REF: DLQ4148

A Admissible repetitive peak forward current versus pulse duration

